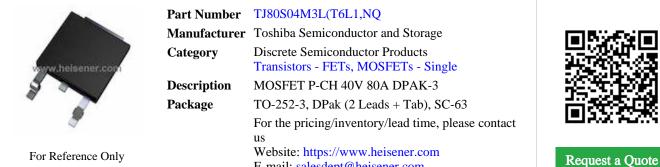


TJ80S04M3L(T6L1,NQ

TJ80S04M3L(T6L1,NQ Information



E-mail: salesdept@heisener.com

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



TJ80S04M3L(T6L1,NQ Specifications

Manufacturer Part Number	TJ80S04M3L(T6L1,NQ
Manufacturer	Toshiba Semiconductor and Storage
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	U-MOSVI
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	40V
Current - Continuous Drain (Id) @ 25°C	80A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Vgs(th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	158nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	7770pF @ 10V
Vgs (Max)	+10V, -20V
FET Feature	-
Power Dissipation (Max)	100W (Tc)
Rds On (Max) @ Id, Vgs	5.2 mOhm @ 40A, 10V
Operating Temperature	175°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	DPAK+
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

TJ80S04M3L(T6L1,NQ Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

TJ80S04M3L(T6L1,NQ Payment Methods



TJ80S04M3L(T6L1,NQ Shipping Methods



If you have any question about TJ80S04M3L(T6L1,NQ, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com